

SES	С	W.MAGNETRO	DN	ISS	UED
323	FOR	MICROWAVE (OVEN	2008.02	2.27.
CUSTOMER SPECIFICATION OM 52S (61)					
<proh b="" deplet="" dn="" ii="" ng="" ozone="" substances="" to="" use=""> Prohibited substances : CFC/Habn/Carbon tetrachbride/1,1,1.Trichbroethane(Methy 1 chbroform) ① This Product, Assembly, or Component does not contain any of the substances above mentioned. ② This Product, Assembly, or Component is not manufactured using any of the substances above mentioned.</proh>					
COMPLED	BY :				
APPROVED					
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1. GENERAL

The SAMSUNG OM52S series is a continuous wave cooking magnetron with fixed frequency of 2465MHz and high efficiency. This magnetron is intended for use in microwave ovens with typical oven power $450\sim550$ watts.

2. TYPICAL CHARACTER ISTICS

2-1 ELECTRICAL

Power SupplyLC stabilized ha	alfwave doubler
Frequency	2465 MHz
Peak Anode Voltage	38 KV
Mean Anode Current	200 mA
Output Power (VSW R \leq 1.1)	570 W
Efficiency	
Filament Voltage	35 V
Cold Filament Resistance	0.047 <u>0</u>
Pre-heating Time	0 sec

2-2 MECHANICAL

Mount Position (note 1)	Any
RF Coupler	WR 430 system
Magnetic System	Ferrite magnet packaged
Weight	0.74 Kg (1.6 bs)
Dimensions	see outline drawing
Cooling A ir F bw	
Pressure Drop	
Cooling Direction	Transverse

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3. ABSOLUTE MAXMUM RATNGS

	Max.
Filament Voltage	3.95 V
Mean Anode Current	250 mA
Peak Anode Current	1000 mA
Anode Temperature (note #2)	300 °C
(at the point indicated on the outline drawing)	
Load V.S.W.R (note #3)	4
Storage Temperature	+ 60 °C
Filter Case Temperature	120 °C
Antenna Temperature	360 °C
Magnetron Output Power	610 w
Starting Time	3 sec

NOTES

- #1. See 11/13 page.
- #2. In an abnormal operation, the maximum allowable temperature for anode is 340° C, provided that dwell time of the maximum temperature does not exceed 2 hours per operation nor 25 hours in total.
- #3. The bad condition in which instantaneous V.S.W.R is 4 through 10 may be allowed only if the dwell time in that is short.

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4. TEST SPECIFICATION

4-1. ELECTRICAL TEST

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TERM	Vf (V)	Va (∛)	h (nA)	VSWR	Notes	M in.	Mean	Max.	Unit	Notes
Cold Insulation Resistance	0	1kv.dc	-	-	-	5M.Q	-	00		
Breakchwn Voltage	Ο		-	-						#1
Cold start(Voltage transient)	35	+8Ac-	200	\leq 11	#2			8	kV	#5
Frequency	35	-	200	≤ 11	#2	2455	2465	2475	MHz	
Peak Anode Vollage	35	-	200	≤ 11	#2	36	38	40	kV	
Effciency	35	-	200	≤ 11	#2		72		%	
Mæn Output Power(1)	35	38	200	≤ 11	#2	530	570	610	W	
Em ission Stability (Vfn)			200	≤ 11	#2			25	V	#3
Stability	35				#4	4			V S WR	#6
Pulling Figure	35		200	13				10	MHz	#6
Filament Current	35	-	-	-		9	11	13	А	
Sirk Phase (at L=4)	35	-	200	4		026	029	032	λsin⁄λg	

4-2. VISUAL & MECHANICAL

1) Major Defects:

Any physical error, om ission or dimensional deviation that affects the component function, fit or reliability.

2) M inor Defects :

Any physical error, on ission or dimensional deviation that is purely aesthetic and does not affect function, fit or reliability.

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4-3. LABEL

Unless otherwise agreed with individual customers, a standard SAMSUNG label will be provided on the filter box of the tube.

4-4. DESIGN OR CONSTRUCT DNAL CHANGES :

SAM SUNG will notify the customer in writing of any major design or constructional changes which either change the performance of the magnetron or have an influence on the mechanical or appearance of the tubes.

Together with the notification sample, test data, and reason for modification will be sent to the customer for approval.

4-5.NOTES

#1. - If during the first snap-on there is evidence of a breakdown within 5 seconds of H.V. application, the test should be repeated once and there should be no indication of breakdown again. (1 breakdown \leq 400 μ A, Series resistance 50K.Q)

#2. - For power supply an L.C., single phase half wave doubler should be used.

- The filament voltage should be measured at tube terminals.
- The combination of transformer and capacitor should be chosen such that for normal line voltage, Ia mean= $200mA \pm 1\%$ and Ia peak 1020 to 1050mA.

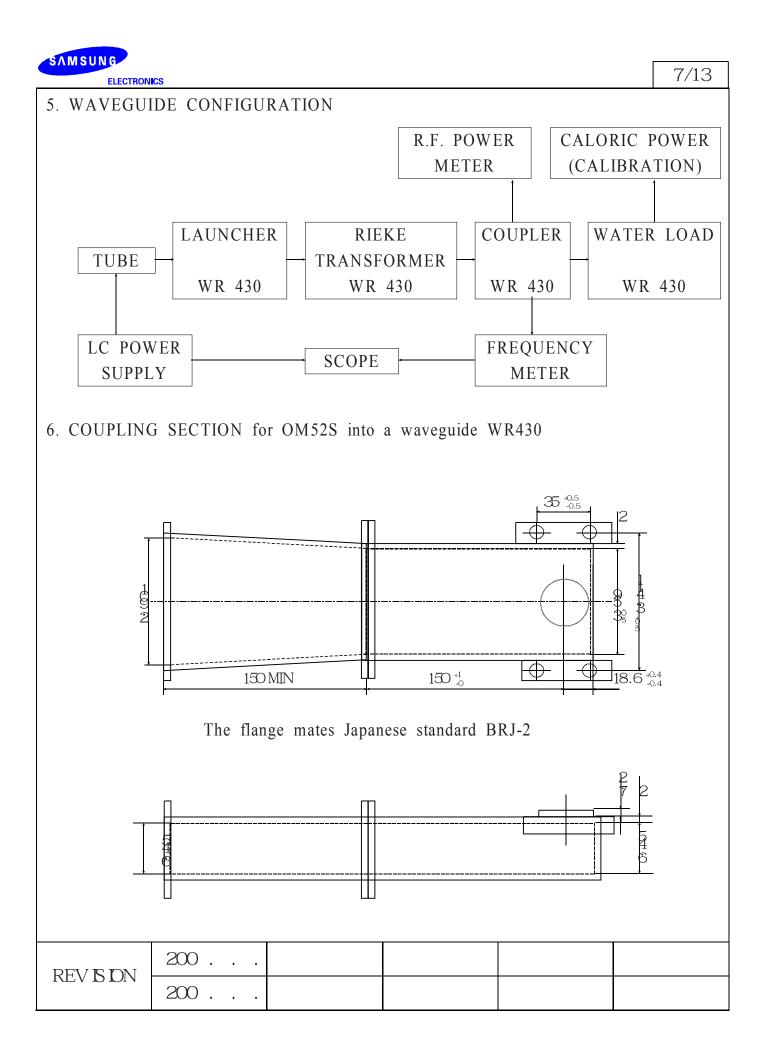
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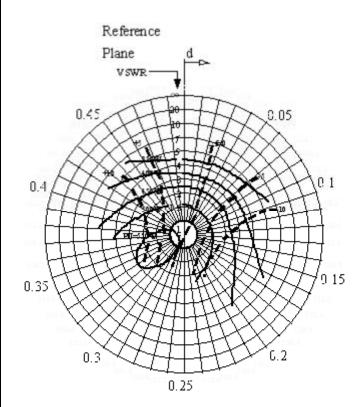
- For wave guide configuration and power supply, see page 7 and 10.
- A water bad of which the VSW $R \le 1.1$ over the frequency band 2425MHz up to 2475MHz should be used.
- Unless otherwise stated, limits apply for a tube within 15 seconds after application of voltage and at $25^\circ\!{\rm C}$.
- Before testing, the tube should be "at room temperature" for at least four hours.
- During test, the magnetron should be cooled with 8001/m in of forced air.
- #3. After a minimum operation of 30 seconds under the specified condition, the filament voltage is gradually decreased. The V fm is the bwest V f value at which the tube is still oscillating in the π mode.
- #4. Starting with minimum operation of 30 seconds at nominal heater voltage and Ia=300mA with VSW R. \leq 1.1 and at 2 λ g distance from the tube, the VSW R.must be increased by means of the Rieke transformer while the phase must be varied in the sink area. The stability is the highest VSW R. at which the tube is still oscillating in the correct π mode.
- #5. Transients are measured on a storage scope during the period 0.5 to 2 seconds after switching on the anode voltage and filament voltage simultaneously.
- #6. Design control tests only.

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SAMSUNG ELECTRONICS

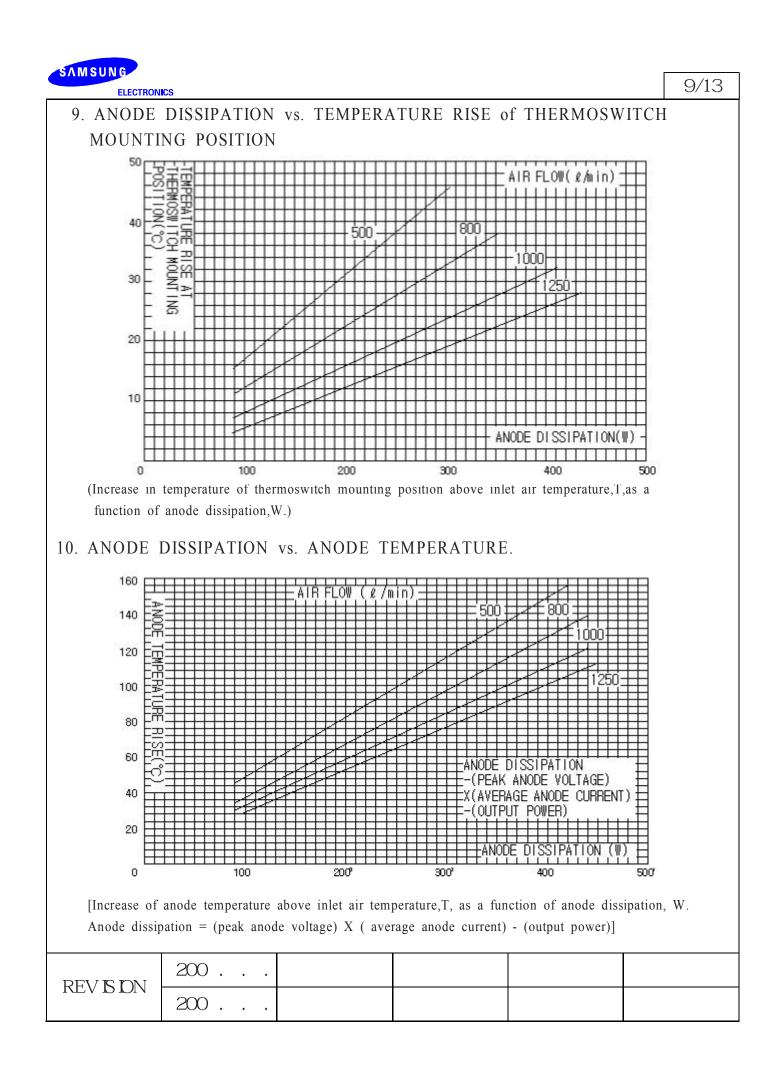
7. RIEKE DIAGRAM IN WAVEGUIDE WR430

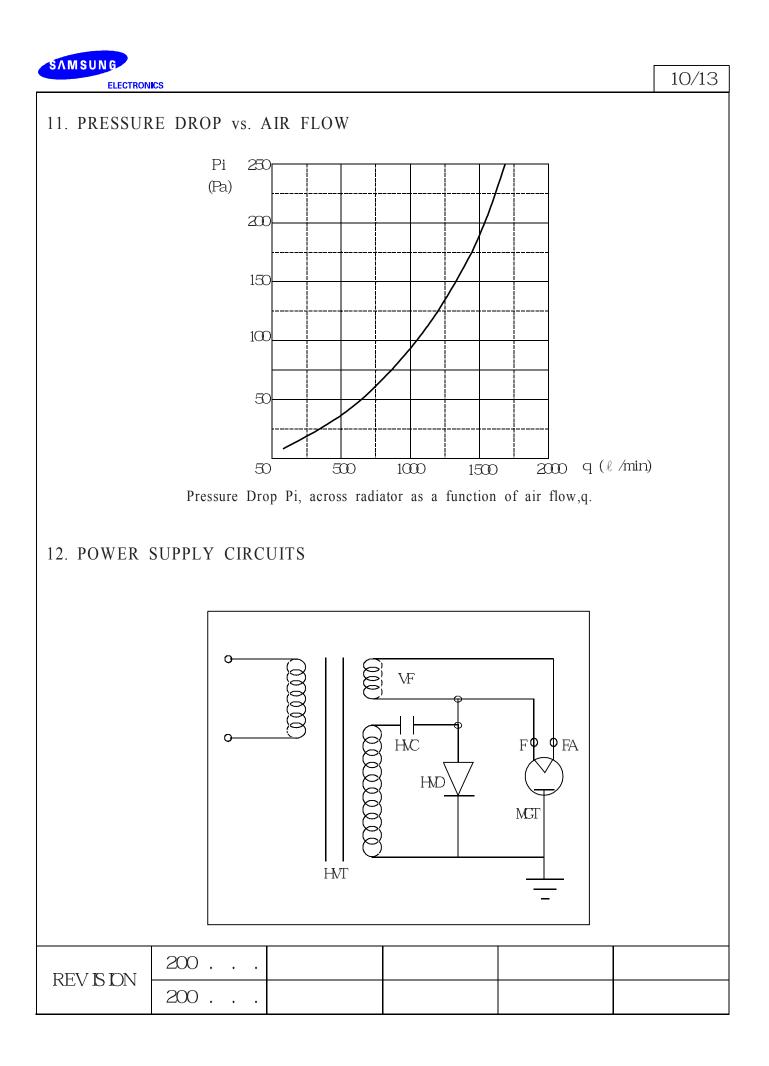


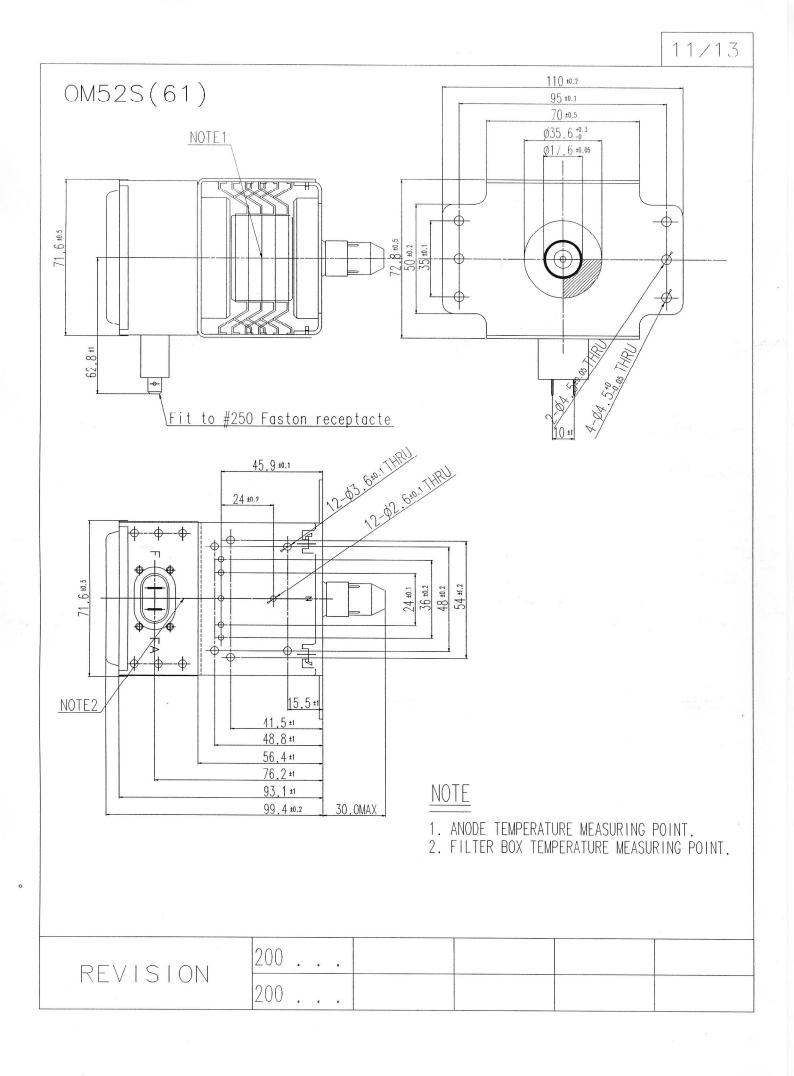
Power Supply : half-wave doubler L.C. type
Filament Voltage 3.5 V
Average Anode Current 200 mA
Peak Anode Voltage 3.8 kV
Frequency at matched load 2465MHz
d : distance of V.S.W.Rminimum from
reference plane towards load
Diagram measured under cold condition

8. PERFORMANCE OF OM52S MAGNETRON

	lap(MA)	
2.48 f (GHz) 2.47 4 2.46 3 2.45 2.45 2.44 1 2.43 0	500 1000 Wo(W) Wo Wo Wo Wo Wo 400 100 200 300 400 Ia(nA)	 Power Supply : single phase half-wave doubler Filament Voltage 3.5 V Load V.S.W.R. 1.1 maximum measured within 15sec. after applying voltage
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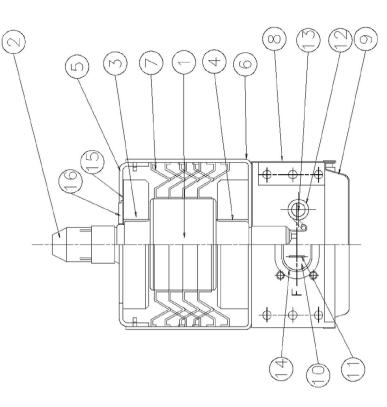




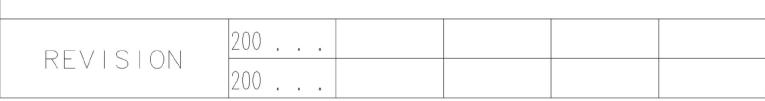


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No.	Part Name	Material
÷	Vacuum Tube	OM52S
2	Cap Antenna	Stainless steel TO.2
3	Magnet	Sr or Ba Ferrite OD55xID21.5xT11
4	Magnet	Sr or Bo Ferrite OD55xID21.5xT13
5	Yoke Output	Steel (Zn Plated) T1.6
9	Yoke Filter	Steel (Zn Plated) T1.4
7	Fin Cooling	Aluminum T0.6
~	Filter Box	Steel (Zn Plated) T0.4
5	Cover Filter	Steel (Zn Plated) T0.4
10	Capacitor	BaTi03 (Epoxy Resin Molded) 10KVdc 500pFx2
11	Faston Tab	Steel
12	Choke Coil	Copper Wire pil.6x15turn 0.3um
13	Core	Ferrite ø5x21mm
14	Cover	Polybutylene-Telephthalate or Unsaturated Polyester 23.5x13.5x20 T : 1
15	Base Gasket	Alsta
16	R/F Gasket	Brass



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Insulating distances in the filt is smithed in the fi	-
	Detter than U.Imm to avoid microwave leakage. 2. Recommended pressure on gasket is 20 to 40 kg.
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lter box of OM52S

